RoHS
Available on commercial versions

Thinkey™ Silicon Schottky Diode

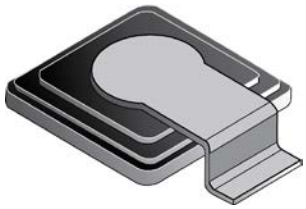
Qualified per MIL-PRF-19500/723

Qualified Levels:
JAN, JANTX, and JANTXV

DESCRIPTION

This Defense Logistics Agency (DLA) qualified Schottky diodes offer great value for aerospace and defense applications requiring high density power and excellent heat dissipation (typically 0.85 - 0.95 degrees C per Watt (C/W)). The 1N6910UTK2AS through 1N6912UTK2AS device polarity is anode-to-strap (standard) and is also available optionally in 1N6910UTK2CS through 1N6912UTK2CS as cathode-to-strap. This part can also be ordered in a strapless version. Up-screening for high-reliability applications is also available. Microsemi also offers numerous other products to meet higher and lower power voltage regulation applications.

Important: For the latest information, visit our website http://www.microsemi.com.



ThinKey™ 2 Package

FEATURES

- JEDEC registered 1N6910 – 1N6912 number series.
- Oxide passivated structure.
- Guard ring protection for increased reverse energy capability.
- Epitaxial structure minimizes forward voltage drop.
- Hermetically sealed, low profile ceramic surface mount power package.
- JAN, JANTX, and JANTXV qualifications are available per MIL-PRF-19500/723. (See part nomenclature for all available options).
- RoHS compliant versions available (commercial grade only).

APPLICATIONS / BENEFITS

- Low package inductance.
- Very low thermal resistance.
- Also available with no strap as 1N6910UTK2, 1N6911UTK2 and 1N6912UTK2 by special request.
- Rugged ceramic and metal construction with no wire bonds.
- High surge capabilities and enable double-side cooling.

MAXIMUM RATINGS @ T_C = +25 °C, unless otherwise noted

Parameters / Test Conditions	Symbol	Value	Unit
Junction and Storage Temperature Range	T_j and T_{stg}	-65 to +150	°C
Thermal Resistance Junction to Case (Anode-to-Strap)	$R_{\Theta JC}$	0.85	°C/W
Thermal Resistance Junction to Case (Cathode-to-Strap) (Also applicable to strapless option)	$R_{\Theta JC}$	0.95	°C/W
Working Peak Reverse Voltage: 1N6910UTK2,CS,AS	V_{RWM}	15	V
1N6911UTK2,CS,AS		30	
1N6912UTK2,CS,AS		45	
Average Rectified Output Current, T_C = +100 °C	I_O	25	A
Non-repetitive Peak Surge Current (tp = 8.3 ms, half sine-wave)	I_{FSM}	400	A (pk)

MSC – Lawrence
6 Lake Street,
Lawrence, MA 01841
Tel: 1-800-446-1158 or (978) 620-2600
Fax: (978) 689-0803

MSC – Ireland
Gort Road Business Park,
Ennis, Co. Clare, Ireland
Tel: +353 (0) 65 6840044
Fax: +353 (0) 65 6822298

Website:
www.microsemi.com

MECHANICAL and PACKAGING

- CASE: Ceramic-molybdenum Thinkey 2.
- TERMINALS: Tin/lead solder or RoHS compliant matte/tin (on commercial grade only) plating.
- MARKING: Part number and polarity symbol.
- POLARITY: Standard is anode to strap. Reverse is cathode to strap.
- WEIGHT: Approximately 0.5 grams.
- See package dimensions on page 4.

PART NOMENCLATURE

JAN 1N6910 U TK 2 AS (e3)

Reliability Level
JAN = JAN level
JANTX = JANTX level
JANTXV = JANTXV level
Blank = Commercial

JEDEC type number
(See Electrical Characteristics table)

Surface Mount package

RoHS Compliance
e3 = RoHS compliant (available on commercial grade only)
Blank = non-RoHS compliant

Polarity
AS=Anode to Strap (standard)
CS=Cathode-to-Strap
Blank=No Strap

Package Size

Package Class

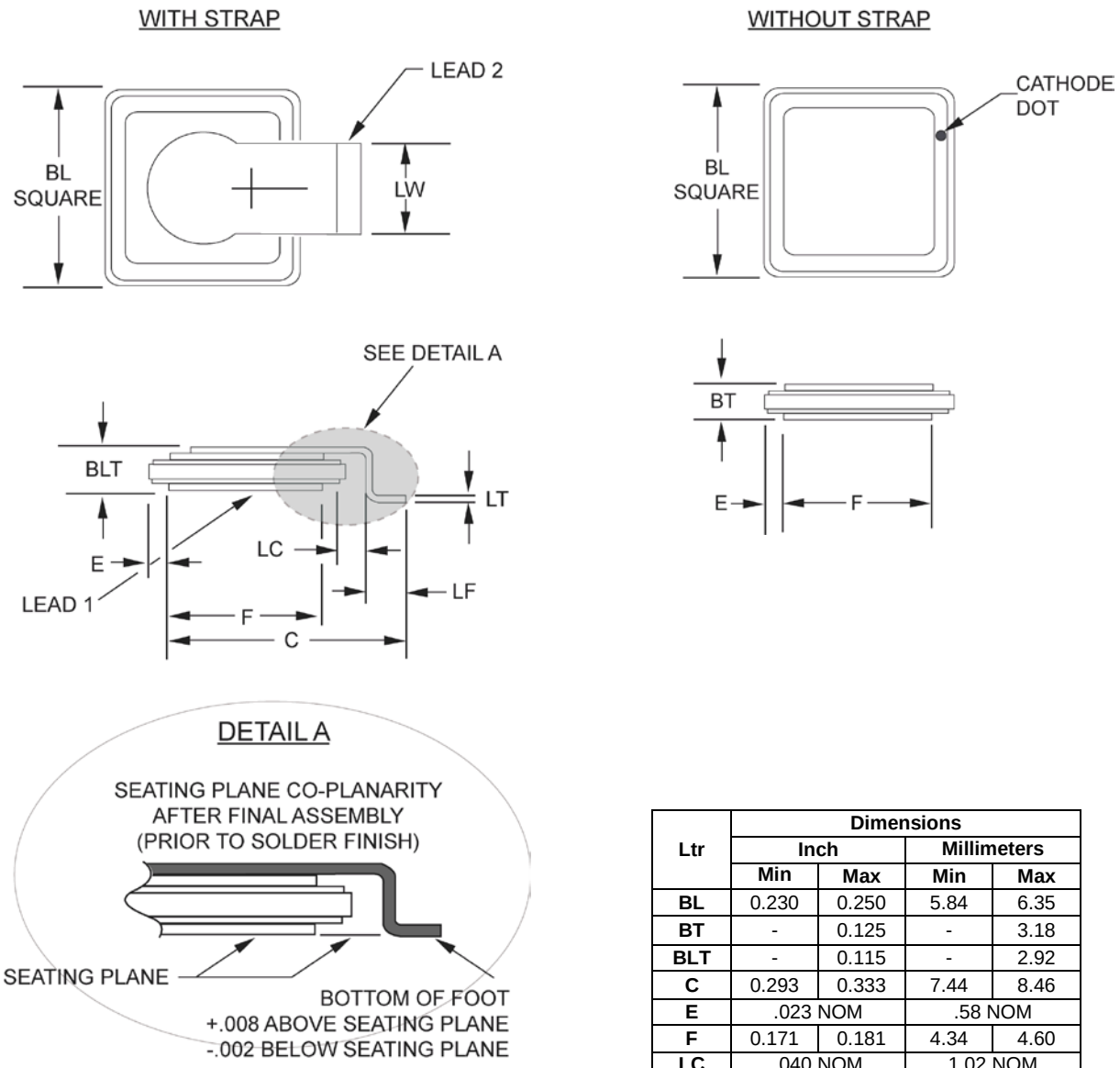
SYMBOLS & DEFINITIONS

Symbol	Definition
f	frequency
I_F	Forward current, dc
I_R	Reverse current, dc
T_C	Case temperature
t_p	Pulse time
V_R	Reverse Voltage, dc

ELECTRICAL CHARACTERISTICS @ T_A = +25 °C, unless otherwise noted

Parameters / Test Conditions		Symbol	MIN	MAX	Unit
Reverse (Leakage) Current					
V_R = 15 V, Tc = 25 °C	1N6910UTK2, CS, AS				
V_R = 30 V, Tc = 25 °C	1N6911UTK2, CS, AS	I_{R1}		1.2	mA
V_R = 45 V, Tc = 25 °C	1N6912UTK2, CS, AS				
V_R = 15 V, Tc = +125 °C	1N6910UTK2, CS, AS				
V_R = 30 V, Tc = +125 °C	1N6911UTK2, CS, AS	I_{R2}		250	mA
V_R = 45 V, Tc = +125 °C	1N6912UTK2, CS, AS				
Forward Voltage					
Pulse test, pulse width tp = 300 µs					
	1N6910UTK2, CS, AS			0.43	
I_F = 10 A (pk), T_C = +25 °C	1N6911UTK2, CS, AS	V_{F1}		0.42	V
	1N6912UTK2, CS, AS			0.52	
	1N6910UTK2, CS, AS			0.52	
I_F = 25 A (pk), T_C = +25 °C	1N6911UTK2, CS, AS	V_{F2}		0.54	V
	1N6912UTK2, CS, AS			0.64	
	1N6910UTK2, CS, AS			0.46	
I_F = 25 A (pk), T_C = +125 °C	1N6911UTK2, CS, AS	V_{F3}		0.55	V
	1N6912UTK2, CS, AS			0.63	
	1N6910UTK2, CS, AS			2000	
Junction Capacitance	1N6911UTK2, CS, AS	C_J		1250	pF
V_R = 5 V, f = 1 MHz, V_{SIG} = 50 mV (p-p)	1N6912UTK2, CS, AS			1000	
Breakdown Voltage					
Pulse test, tp = 35 ms					
	1N6910UTK2, CS, AS		16.5		
I_R = 5.0 mA (pk), T_C = 25 °C	1N6911UTK2, CS, AS	$V_{(BR)1}$	33		V
	1N6912UTK2, CS, AS		50		
	1N6910UTK2, CS, AS		15		
I_R = 5.0 mA (pk), T_C = -55 °C	1N6911UTK2, CS, AS	$V_{(BR)2}$	30		V
	1N6912UTK2, CS, AS		45		

PACKAGE DIMENSIONS



Ltr	Dimensions			
	Inch		Millimeters	
	Min	Max	Min	Max
BL	0.230	0.250	5.84	6.35
BT	-	0.125	-	3.18
BLT	-	0.115	-	2.92
C	0.293	0.333	7.44	8.46
E	.023 NOM		.58 NOM	
F	0.171	0.181	4.34	4.60
LC	.040 NOM		1.02 NOM	
LF	0.055	0.075	1.40	1.91
LT	0.005	0.015	0.127	0.381
LW	0.085	0.115	2.16	2.92

NOTES:

1. Dimensions are in inches.
2. Millimeters are given for general information only.
3. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

SEE PAD LAYOUT ON NEXT PAGE.

PAD LAYOUT